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# Exploring the bifunctional properties of paper-like carbyne-enriched carbon for maintenance-free self-powered systems†

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Self-powered systems (SPSs) have become promising power sources in this modern era mainly due to their ability to harvest and store energy in a single system. Herein, we report the bifunctional properties of a free-standing paper-like carbyne-enriched carbon (P-CEC) film (derived from dehydrohalogenation of PVDF) that can be used as an energy harvester (triboelectric nanogenerator) and storage unit (supercapacitor) in SPS. The changes in work function and surface potential of the P-CEC film after the dehydrohalogenation process were carefully investigated via Kelvin probe force microscopy (KPFM) and ultraviolet photoelectron spectroscopy (UPS). The fabricated P-CEC TENG generated a peak-to-peak voltage of  $\sim 126$  V (with an applied force of 15 N), which is superior compared to the state-of-the-art of polymer-based TENG. Furthermore, the fabricated P-CEC symmetric supercapacitor (SSC) possess an excellent energy density ( $109$  nW h cm<sup>-2</sup>), power density ( $2200$   $\mu$ W cm<sup>-2</sup>) and a long cycle-life. The integration of P-CEC-based TENG and SSC into an effective SPS unit demonstrated the ability of TENG to charge the SSC up to 750 mV within 380 s. These results show that the development of bifunctional materials such as P-CEC has a great potential for the maintenance-free SPS systems.

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## 1. Introduction

The rapid advancement of multifunctional consumer gadgets (power banks, smart-watches, E-skin, smart glasses, smart-phones, etc.) in this era has triggered researchers to focus on clean and sustainable power sources.<sup>1–4</sup> Batteries (Li-ion, Li-polymer, alkaline, and nickel metal hybrids) are the most commonly used power sources for driving smart gadgets.<sup>5</sup> Naturally, society is moving towards smaller, thinner, and more comfortable gadgets compared to huge and rigid devices. Accordingly, smart electronics use power sources that are firm and one-third of the gadget weight. Moreover, key issues with these power sources (used in smart gadgets) are their limited lifetime, frequent replacement/charging, toxicity, high cost, and risk of explosion.<sup>6</sup> Energy conversion/harvesting and electrochemical storage device are the two important aspects of providing sustainable power sources for gadgets, but they are two independent units with distinct working mechanism.<sup>7</sup> The concept of integrating energy

harvesting and storage devices in a single system without the power management circuit (PMC) and the so-called self-powered system (SPS) is a relatively novel concept developed for maintenance-free smart gadgets.<sup>8</sup> Among the various energy harvesting techniques, triboelectric nanogenerator (TENG) has attracted much attention due to its unique advantages of high energy output (voltage/current), lightweight, easy to construct, and wide material choice.<sup>9</sup> However, TENG delivers a pulsed output, which make them unsuitable for driving smart gadgets. Therefore, the output of TENG can be stored in energy storage devices and can be used to drive gadgets for which SPSs need to be formulated.<sup>10</sup> Considering the energy storage, supercapacitors (SCs) are promising candidates due to their merits such as lightweight, moderate energy/maximal power density, rapid charging/discharging, and long-run cycle life. To reduce the manufacturing cost (in terms of materials) for SPSs, it is desirable to develop unique materials that can harvest and store energy. To the best of our knowledge, to date, no study has demonstrated the use of a single active material acts as both energy harvester and storage unit in a SPS.<sup>11–15</sup> The ongoing research is focused on this issue to develop novel materials with bifunctional properties (harvesting and storage) in SPSs.

In this scenario, carbon-based materials are broadly used in mechanical energy harvesters (nanogenerators) and energy storage devices (batteries and supercapacitors) due to their

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natural abundance, eco-friendly nature and low cost.<sup>16–19</sup> The properties of carbon-based materials vary depending on their allotropic nature ( $sp^3$  hybridized (diamond),  $sp^2$  hybridized (CNTs and graphene)) and their structures.<sup>20,21</sup> Linear monoatomic chains of  $sp$ -hybridized carbon are new potential carbon allotropes, and their bulky form is termed carbyne.<sup>22</sup> Earlier studies suggested that carbyne is naturally available in marine sources, shock-fused graphite, meteorites, and interstellar dust.<sup>23</sup> The existence of carbyne and its vital properties have been studied theoretically and on laboratory-scale experiments to date.<sup>24</sup> Recently, different groups prepared carbyne-like carbons, which typically consist of  $sp$ -hybridized carbyne chains embedded in  $sp^2/sp^3$  carbon matrix.<sup>22</sup> However, the curious case of carbyne is highly dubious among researchers regarding the presence of pure  $sp$ -hybridized carbyne materials.<sup>25</sup> Beyond these debates, many researchers have explored the synthetic routes and fascinating properties of carbyne in recent decades.<sup>26</sup> Our recent study on free-standing carbyne revealed their mechanical-to-electric energy conversion properties.<sup>16</sup> These studies motivated us to explore the fundamental properties of flexible paper-like carbyne-enriched carbon (prepared *via* the dehydrohalogenation method) and their use as both triboelectric nanogenerator and energy storage unit in a formulated SPS for the first time.

## 2. Results and discussion

### 2.1 Preparation and characterization of P-CEC films

Fig. 1 presents a schematic illustration for the preparation of the free-standing paper-like carbyne-enriched carbon (P-CEC). Polyvinylidene fluoride (PVDF) is a stand-alone candidate, which has received much attention among the polymers due to its exceptional chemical resistance and high mechanical strength.<sup>27</sup>

This made it suitable as a starting material for the development of new conductive P-CEC films *via* a one-step dehydrohalogenation reaction.<sup>25</sup> The PVDF film prepared *via* the solvent-casting method was subjected to the dehydrohalogenation process using potassium ethylate in tetrahydrofuran solution. The transformation of the white film into a metallic black film after the dehydrohalogenation process confirmed the formation of the new conductive P-CEC film, as seen in the digital photograph presented in Fig. 1. Fig. 2 displays the physicochemical characterization of the prepared P-CEC film. The comparative X-ray diffractograms (XRD) of the PVDF and P-CEC films are depicted in Fig. 2(A). The XRD pattern of the PVDF film shows a broad peak at  $2\theta = 20.3^\circ$ , which is ascribed to the  $\beta$ -phase (orthorhombic structures), while the minor peak (shoulder) at  $2\theta = 18.4^\circ$  corresponds to the monoclinic structure of the  $\alpha$ -phase. The P-CEC film obtained from PVDF *via* the exclusion of halogen exhibited a similar diffraction pattern to that of the PVDF film, suggesting that the removal of the halogen did not affect its crystallinity.<sup>16,28</sup> To evaluate the changes in surface elemental composition and valence state of the PVDF film before and after the exclusion of halogen *via* the dehydrohalogenation reaction, X-ray photoelectron spectroscopy (XPS) was performed. Fig. 2(B) displays the comparative XPS full-scale survey spectra of the PVDF and P-CEC films. The survey spectrum of PVDF reveals the presence of carbon and fluorine components. It was observed that after the exclusion of halogen *via* the dehydrohalogenation process, the intensity of the fluorine component significantly decreased with an increase in the intensity of the carbon component compared to that of former, which confirms the formation of the P-CEC film.<sup>25</sup> The relative C 1s core level spectra of the PVDF and P-CEC films are shown in Fig. S1 (ESI†). The C 1s spectrum of PVDF reveals the presence of C–C and C–F, corresponding to the peaks located at 285.5 and 290.5 eV, respectively.<sup>29</sup> After the formation of the

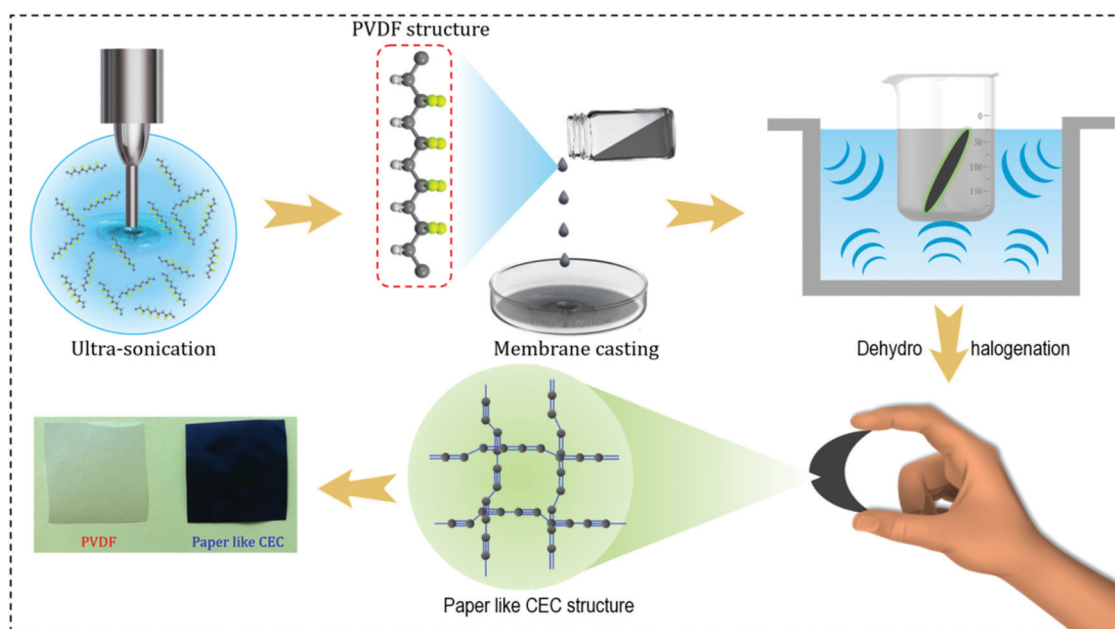


Fig. 1 Graphical representation of the steps involved in the fabrication of the free-standing paper-like carbyne-enriched carbon film.



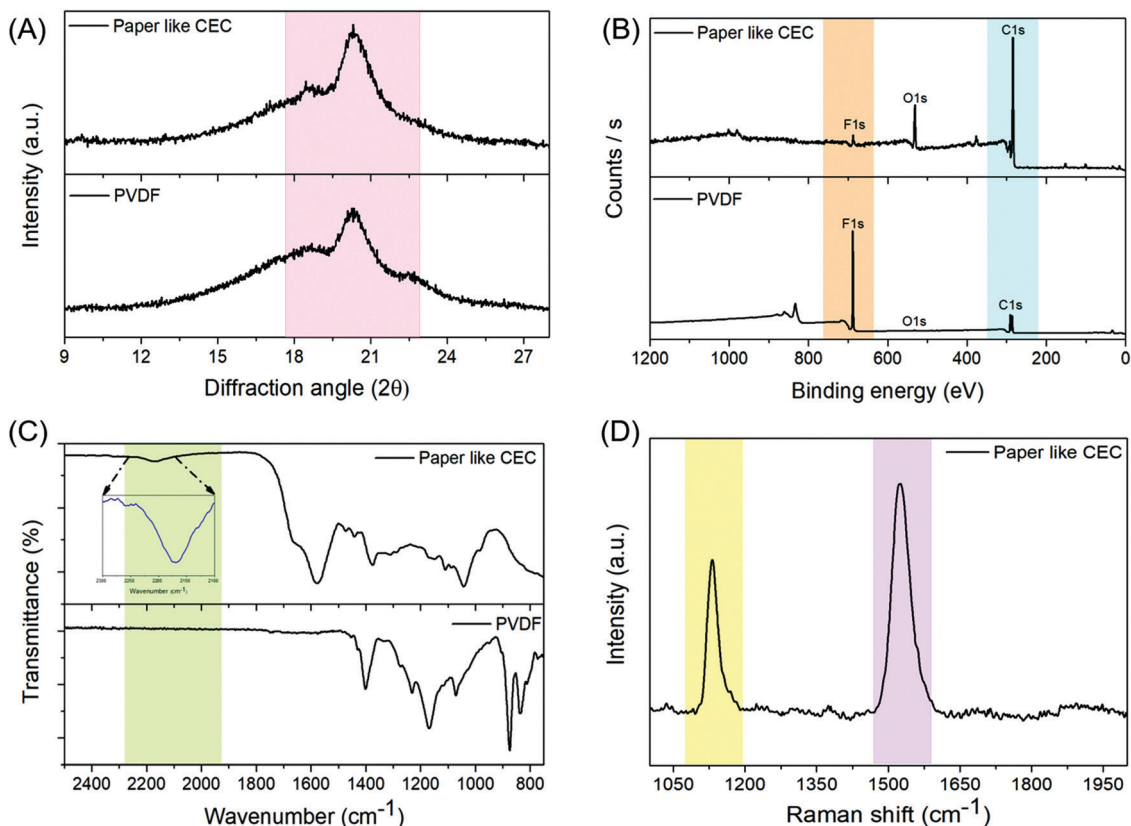


Fig. 2 Physicochemical characterization of the prepared P-CEC film. (A) Comparative XRD spectra of the PVDF and P-CEC films, (B) relative XPS survey spectra of the PVDF and P-CEC films, (C) comparative FT-IR spectra of the PVDF and P-CEC films, and (D) laser Raman spectrum of the P-CEC film.

P-CEC film *via* the exclusion of halogen, the C–C peaks slightly shifted and narrowed while the C–F peaks significantly decreased compared to the PVDF film. These results suggest the formation of P-CEC from the PVDF film. Fig. 2(C) shows the change in the Fourier infra-red spectrum (FT-IR) after the exclusion of halogen from PVDF *via* the dehydrohalogenation process. The vibration bands of PVDF located at 877.3, 839.02, and 1232  $\text{cm}^{-1}$  correspond to the  $\alpha$ -,  $\beta$ - and  $\gamma$ -phase, respectively.<sup>30</sup> After the exclusion of halogen, significant changes were observed in the P-CEC film as follows: (i) the vibrational bands of PVDF at 1399, 1157, and 1067  $\text{cm}^{-1}$  shifted to a lower wavenumber, which may be due to the exclusion of halogen and (ii) two new band were observed at 1578 and 2166  $\text{cm}^{-1}$  mainly attributed to the carbon-carbon vibrations in the polynne structure.<sup>31</sup> This result is in good agreement with the previous report.<sup>16</sup> The laser Raman spectroscopy study was carried out to examine the structural and functional changes that occurred after the formation of P-CEC from the PVDF film *via* the dehydrohalogenation process. Fig. S2 (ESI<sup>†</sup>) depicts the laser Raman spectrum of the PVDF film, which shows the characteristic bands at 807.9 and 844.8  $\text{cm}^{-1}$ , corresponding to the  $\alpha$ - and  $\beta$ -phase of the prepared PVDF film, respectively, while the peak at 886.7  $\text{cm}^{-1}$  corresponds to the vibration of the C–F and C–C vibrational bands of the PVDF film.<sup>32</sup> After the exclusion of halogen from the PVDF film *via* the dehydrohalogenation process, the laser Raman spectrum of prepared P-CEC film showed two major peaks at

1133.6 and 1530.5  $\text{cm}^{-1}$ , as seen in Fig. 2(D). The band observed at 1133.6  $\text{cm}^{-1}$  is attributed to the presence of beta carbyne, whereas the peak at 1530.5  $\text{cm}^{-1}$  corresponds to the vibration of the carbon networks.<sup>16,33</sup>

Fig. 3 depicts the change in surface morphology upon the conversion of the PVDF film to P-CEC. The cross-sectional images of the PVDF and P-CEC films are shown in Fig. 3(A and B), respectively, which revealed that the removal of halogen from PVDF did not affect the thickness of the P-CEC film. The corresponding elemental mapping of the PVDF and P-CEC films is depicted in Fig. S3 and S4 (ESI<sup>†</sup>), respectively, which further confirms that the dehydrohalogenation process resulted in the removal of halogen (fluorine) from the P-CEC film. Fig. S5(A–C) (ESI<sup>†</sup>), presents the FE-SEM micrographs of the PVDF film at different magnifications, suggesting its uniform and dense surface with no visible voids on the film. To examine the purity and distribution of the film, the elemental mapping analysis was carried out, as shown in Fig. S5(D) (ESI<sup>†</sup>). The overlay map reveals the existence of C and F elements in the PVDF film. Moreover, the C and F elements are uniformly distributed throughout the film, as seen in Fig. S5(E and F) (ESI<sup>†</sup>). The FE-SEM micrograph of the P-CEC film after the removal of halogen is shown in Fig. 3(C). It revealed the presence of voids and uniform surface in the prepared P-CEC film after the dehydrohalogenation reaction, suggesting the removal of halogen from PVDF film. To check the distribution and purity of the prepared P-CEC film, elemental mapping analysis was





**Fig. 3** FE-SEM analysis of the prepared P-CEC film. (A) Cross-sectional FE-SEM image of PVDF, (B) cross-sectional FE-SEM micrograph of the P-CEC film after the exclusion of halogen, (C) FE-SEM micrograph of the P-CEC film, (D) EDS spectrum of C, O and F present in the P-CEC film, and (E) overlay map of the P-CEC film obtained using elemental mapping analysis. (F–H) Elemental mapping of C, O and F present in the P-CEC film. (I–L) Pictorial representation of the prepared P-CEC film showing its bending (J), twisting (K) and folding (L) ability.

carried out, as shown in Fig. 3(D–H). The EDS spectrum presented in Fig. 3(D) reveals the ratio of the C, F and O elements present in the prepared P-CEC film. The overlay map of the P-CEC film shows the presence of the C, F, and O elements, as seen in Fig. 3(E), and their corresponding mapping elements are shown in Fig. 3(F–H), respectively, revealing the formation of the P-CEC film. Moreover, the P-CEC film was free-standing with excellent flexibility, which could be bent, twisted and folded freely to form any shape. For example, the digital photograph of the P-CEC film (Fig. 3(I)) shows it could be easily bent (Fig. 3(J)), twisted (Fig. 3(K)) and folded (Fig. 3(L)) according to our requirements. In addition, the elimination of the current collector in the prepared P-CEC film reduced the weight of the device, which significantly increased the energy conversion and storage performances of the device.

## 2.2 Energy harvesting properties of P-CEC TENG

To evaluate the real-time application of the as-prepared P-CEC film, we have examined its use as an active layer in a triboelectric nanogenerator (TENG) and active electrode material for a symmetric supercapacitor (SSC) considering the state-of-the-art for maintenance-free self-powered system (SPS). Initially, we examined the as-prepared free-standing and flexible P-CEC film directly as a tribo-layer for the fabrication of a TENG. We investigated the surface charge of the obtained film using kelvin probe force microscopy (KPFM) in non-contact mode. Fig. 4(A) and (B) depict the 2D mapping of the surface potential of the PVDF and P-CEC films using Pt tips. Excitingly, after the exclusion of halogen from the PVDF film *via* the dehydrohalogenation process, the surface charge of the P-CEC film shifts

towards a high positive potential (+250 mV) compared to that of the bare PVDF (−200 mV), as evident from Fig. 4(B). The same phenomenon was observed when graphene was added to a pristine PVDF film, confirming that the obtained P-CEC film is an analogue of carbon.<sup>34</sup> The positive shift in the surface charge potential of the prepared P-CEC film was anticipated to increase the electrical response of the TENG.<sup>35,36</sup> The increase in the surface potential of the P-CEC film (after the exclusion of halogen) was supported by ultra-violet photoelectron spectroscopy (UPS), as depicted in Fig. S6 (ESI<sup>†</sup>). This shift may be due to the change in the work function of the prepared P-CEC film, which can be determined from the difference between the photon excitation energy and spectrum width.<sup>37</sup> From these estimations, the work function of the prepared P-CEC film was found to be 3.37 eV, which is lower compared to that of the pristine PVDF (5.55 eV) and PVDF-G18 (4.84 eV), which is expected to improve the electrical performance of the TENG compared to the bare PVDF film.<sup>34</sup> Based on the above result, we constructed a two-arch-based TENG with (i) P-CEC as the positive layer and Kapton as the negative layer and (ii) PVDF as the negative layer and aluminium as the positive layer to evaluate the changes that occurred in the electrical response of the TENG before and after the dehydrohalogenation process. TENG works on the principle of electrostatic induction and contact electrification, and the triboelectric mechanism of the vertical-contact-mode of the P-CEC TENG is depicted in Fig. 4(C). In the initial stage, each layer of P-CEC TENG has no surface charge with zero electric potential, as shown in Fig. 4(C)(i). Once the external compressive force was applied on the P-CEC TENG, the P-CEC



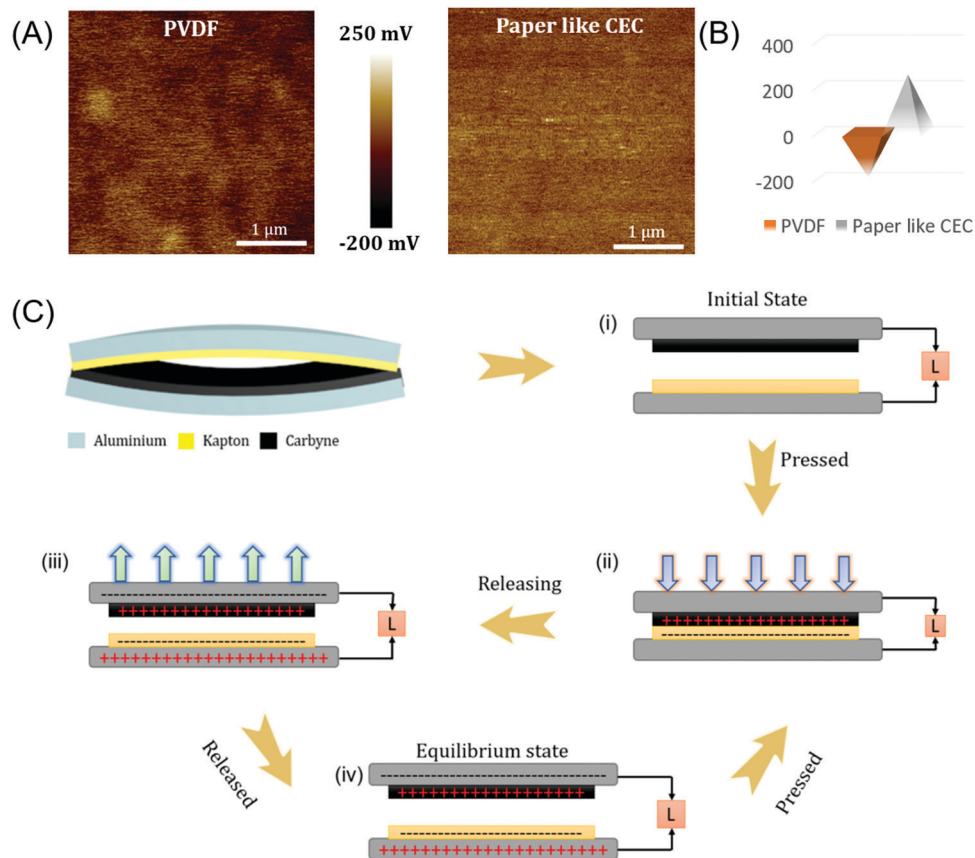


Fig. 4 (A) Surface potential mapping of the PVDF and P-CEC films analyzed *via* KPFM measurement, (B) plot of the change in surface potential before and after the exclusion of halogen, and (C) working mechanism of the P-CEC TENG in the vertical contact-separation mode.

and Kapton tribo-layer came into contact with each other, leading to the production of equal and opposite charge on the surface of the P-CEC TENG (as seen in Fig. 4(C)(ii)) due to tribo-electricity. When the external force was removed, the two layers of P-CEC TENG started to be released to their original position slowly, and this separation led to the creation of a potential difference between the layers of the P-CEC TENG. This potential drove the electron flow from the negative layer (Kapton layer) to the positive layer (P-CEC layer) *via* the external circuit and the maximum electric signal, as shown in Fig. 4(C)(iii). Once the P-CEC TENG was pressed again, electron flow occurred in the opposite direction, which led to the formation of an AC signal, as seen in Fig. 4(C)(iv). When the two layers of P-CEC TENG came into contact, then all the surface charge was neutralized, which resulted in no output.<sup>38,39</sup>

Fig. 5 depicts the electrical response of the P-CEC TENG. Fig. 5(A) and Fig. S7 (ESI<sup>†</sup>) show the comparative electrical output voltage and current profile of the PVDF-based TENG and P-CEC TENG measured at the constant force of 10 N. The P-CEC TENG showed a higher output performance ( $\sim 117$  V and  $\sim 1.2$   $\mu$ A) compared to the PVDF-based TENG ( $\sim 14.6$  V and  $\sim 220$  nA), which may be due to the following reasons: (i) the high surface potential of the P-CEC film compared to the bare PVDF film, (ii) increase in the electrical conductivity of the P-CEC film and (iii) roughness created in the P-CEC film upon

the exclusion of halogen *via* the dehydrohalogenation process compared to that of the PVDF film.<sup>40,41</sup> It is well known that surface roughness plays a vital role in the electrical performance of TENGs, and thus we checked the roughness of the PVDF and prepared P-CEC film *via* AFM analysis, as shown in Fig. S8 (ESI<sup>†</sup>). As expected, the P-CEC film exhibited a higher roughness than the bare PVDF film, which may be one of the reasons for the high electrical performances of the P-CEC TENG. Fig. 5(B and C) present the voltage and current profiles of the P-CEC TENG obtained at different levels of applied force ranging from 2 N to 15 N, respectively. It is noteworthy that the obtained voltage and current of P-CEC TENG ( $\sim 126$  V and  $\sim 1.4$   $\mu$ A) was quite higher compared to that of CNT/PDMS TENG ( $\sim 40$  V and  $\sim 0.8$   $\mu$ A), MoS<sub>2</sub>/nylon TENG ( $\sim 13$  V), MoSe<sub>2</sub>/nylon ( $\sim 5.5$  V), Graphene/PET (5 V), graphene/PDMS (22 V), and other.<sup>42–44</sup> Fig. 5(D) and Fig. S10 (ESI<sup>†</sup>) shows the rectified voltage of the P-CEC TENG at various applied forces. The results show that the P-CEC TENG delivered the maximum rectified voltage of  $\sim 58$  V at an applied compressive force of 15 N. The power and voltage plots of the P-CEC TENG as a function of load resistance are depicted in Fig. 5(E). The maximum power of the P-CEC TENG was  $\sim 27.5$   $\mu$ W ( $9.28$   $\mu$ W cm<sup>-2</sup>) at the load resistance of 0.5 G $\Omega$ , which is higher compared to that of a polymer-based TENG, carbon-based TENG, and recent 2D material-based TENG.<sup>42,45</sup> Fig. 5(F) shows the cyclic test of



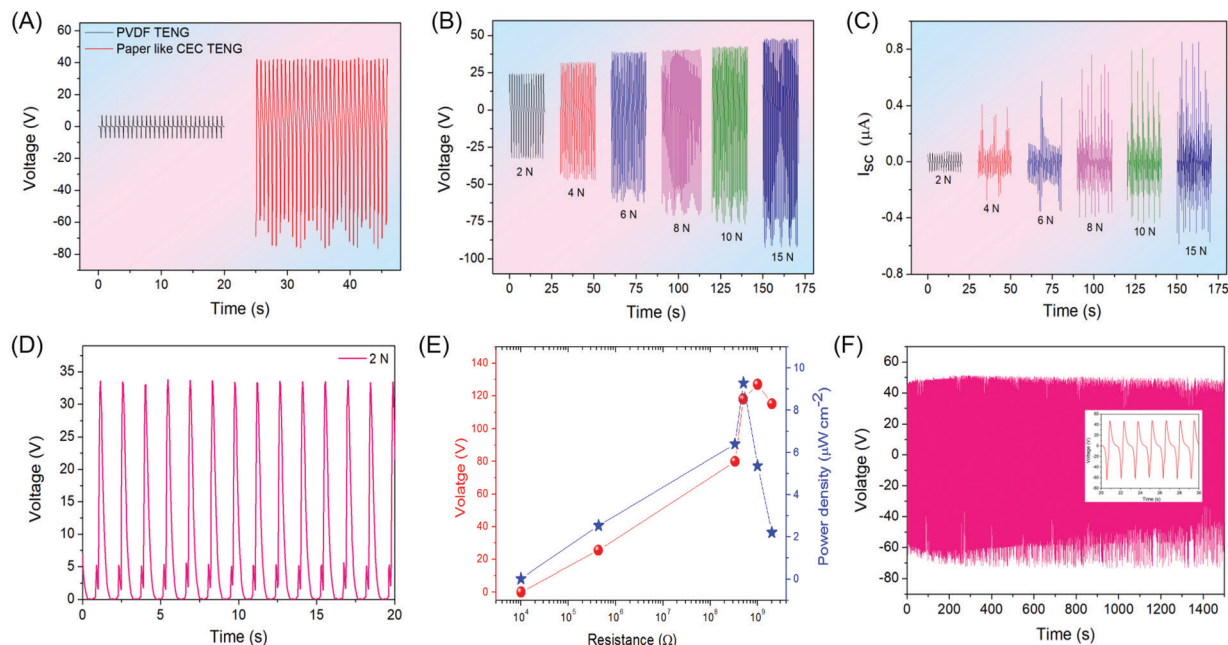


Fig. 5 (A) Relative output voltage of the PVDF and P-CEC-based TENG, (B and C) output voltage and current of the P-CEC TENG as a function of applied compressive force, respectively, (D) rectified voltage of the P-CEC TENG at a constant applied compressive force of 2 N, (E) output voltage and maximum peak power of the P-CEC TENG as a function of load resistance, and (F) endurance test of the P-CEC TENG over 1500 s at a constant applied force.

P-CEC TENG over 1500 s, which showed excellent stability without any decay in electrical output over time.

### 2.3 Electrochemical performance of P-CEC symmetric supercapacitor

The P-CEC film displayed unique micro-pore/meso-pore structures, high conductivity, and excellent flexibility, which can satisfy the critical requirements of flexible supercapacitors.<sup>46,47</sup> Therefore, we also investigated the electrochemical performance of the P-CEC film as a binder-free electrode in the fabrication of a symmetric supercapacitor (SSC) using PVA-Na<sub>2</sub>SO<sub>4</sub> gel electrolyte as the separator.<sup>48</sup> The comparative cyclic voltammetry (CV) profiles of PVDF and P-CEC SSC in the voltage window of 0.0 to 0.8 V were recorded at a scan rate of 100 mV s<sup>-1</sup>, as depicted in Fig. 6(A). As expected, the P-CEC SSC showed better capacitance behaviour compared to the PVDF SSC, which may be due to the unique pore structures and high conductivity of the film. Fig. 6(B) shows the CV profile of the P-CEC film at various scan rates (5 to 100 mV s<sup>-1</sup>), which suggests ideal rectangular behaviour without any change in its curve, indicating the type A capacitive charge storage mechanism.<sup>49</sup> Fig. 6(C) portrays the galvanostatic discharge (GD) profile of the P-CEC SSC measured over the voltage window of 0.8 V at different currents ranging from 0.25 to 5 mA, revealing isosceles triangular behaviour, which is consistent with the CV profile (as seen in Fig. 6(B)). The plot of specific capacitance as a function of discharge current is shown in Fig. 6(D). The specific capacitance of the P-CEC film increased with a decrease in discharge current, which may be due to the time constraint of electrolyte ions on the P-CEC film. The maximum specific capacitance of the P-CEC SSC delivered about 1200 μF cm<sup>-2</sup> at the current of 0.25 mA. The obtained specific capacitance further

confirms the electrochemical behaviour of the P-CEC film since it is known that PVDF is a good insulator and it does not possess electrochemical behaviour. To further analyse the capacitance and resistive behaviour of the P-CEC SSC device, we carried electrochemical impedance spectroscopy (EIS). Fig. S11(A) (ESI<sup>†</sup>) depicts the Nyquist plot of the P-CEC SSC, which consists of an inobtrusive arc (high frequency) and straight Warburg line (low-frequency region), suggesting ideal capacitive behaviour. The equivalent series resistance (ESR) of the PVDF SSC and P-CEC SSC was found to be 788.8 Ω (Fig. S12, ESI<sup>†</sup>) and 7.5 Ω, respectively, suggesting the good electrical conductivity of P-CEC SSC after the exclusion of halogen *via* the dehydrohalogenation process. Fig. S11(B) (ESI<sup>†</sup>) depicts the Bode phase angle plot of the P-CEC SSC device, indicating a phase angle of about -78.9°, which reveals ideal capacitive behaviour similar to that of other carbon supercapacitors. The Ragone chart is depicted in Fig. 6(E) to estimate the overall performance of the flexible solid-state P-CEC SSC. The energy density of the P-CEC SSC reached up to 109 nWh cm<sup>-2</sup> at the low current of 0.25 mA with the maximal power density of 2200 μW cm<sup>-2</sup> at the current of 5 mA. Fig. 6(F) displays the endurance test of the P-CEC SSC device over 10 000 cycles using continuous CD measurement at a current of 1 mA. About 98.3% of its initial capacitance was retained even after 10 000 continuous cycles, suggesting the excellent stability of the device. Fig. S13 (ESI<sup>†</sup>) shows the CV profile of two P-CEC SSC devices connected in series to generate the operating voltage of 1.6 V, suggesting the excellent uniformity of their electrochemical performances. As a proof of concept, the P-CEC SSC devices connected in series were employed to power a blue light-emitting diode, as shown in the inset of Fig. 6(F).





Fig. 6 Electrochemical performance of the P-CEC SSC device. (A) Relative CV profiles of the PVDF SSC and P-CEC SSC devices tested over the scan rate of 100 mV s<sup>-1</sup>, (B) CV profile of the P-CEC SSC device at different scan rates (5 to 100 mV s<sup>-1</sup>), (C) discharge profile of the P-CEC SSC device at various currents in the range of 0.25 to 5.0 mA, (D) variation in the capacitance of the P-CEC SSC device at different currents, (E) ragone chart of the P-CEC SSC device, and (F) cycling performance of the P-CEC SSC device over 10 000 cycles at a constant current of 1 mA.

#### 2.4 P-CEC-based self-powered system

Fig. 7 illustrates the maintenance-free self-powered system using the P-CEC film as both the energy harvester and storage unit. The electric circuit of P-CEC-based SPS is shown in Fig. 7(A). Initially, the ability of the PVDF and P-CEC based

TEG device to charge a commercial capacitor (1 μF) at the constant applied force of 10 N was tested, as seen in Fig. S14 (ESI<sup>†</sup>). It revealed that the P-CEC TENG could charge up to 1.75 V within 32 s, while the PVDF TENG charged only 0.6 mV (50 s), suggesting the extraordinary performance of the former



Fig. 7 Application of P-CEC SPS. (A) Schematic representation of the SPS, (B and C) self-charging properties of the P-CEC SPS under various mechanical force (2 N and 15 N), respectively, and (D) self-charging properties of the P-CEC SPS upon hand flapping.



compared to the latter. We charged the P-CEC SSC with the P-CEC TENG in vertical contact mode at different force of 2 N (Fig. 7(B)), 8 N (Fig. S15, ESI†) and 15 N (Fig. 7(C)). The P-CEC SSC self-charged to about 750 mV within 380 s under the constant applied force of 15 N and self-discharged to around 600 mV in 620 s, which is high compared to other state-of-the-art SPSs, as evident from Table S1 (ESI†). To demonstrate this, a single P-CEC TENG and P-CEC SSC were connected with a bridge rectifier and attached under a human shoe to check the self-powered system under human motions. This P-CEC SPS self-charged up to 680 mV in 32 s and self-discharged to around 400 mV in 89 s, as seen in Fig. 7(D). All these results show that the P-CEC film will be an effective self-powered system (power source) for the development of next-generation wearable and portable electronic gadgets.

### 3. Conclusion

In this study, we successfully demonstrated a maintenance-free system using the bifunctional property of a free-standing paper-like carbyne-enriched carbon film (obtained from a thermoplastic polymer) as both a triboelectric nanogenerator and supercapacitor for the first time. The exclusion of halogen from PVDF and formation of the P-CEC film were systematically characterized *via* XRD, laser Raman spectroscopy, XPS, and FE-SEM analysis. The change in the work function and surface potential of the P-CEC film was methodically analyzed *via* KPFM and UPS measurement, and the P-CEC TENG delivered the electrical output of ~126 V and ~1.4  $\mu$ A with outstanding stability. The electrochemical properties of P-CEC SSC were superior to that of the PVDF SSC. Furthermore, the SPS (integrated P-CEC TENG and P-CEC SSC) unit showed a superior charge storage property (750 mV within 380 s) compared to state-of-the-art self-powered systems. Herein, we successfully demonstrated the bi-functional properties of a free-standing P-CEC film as a self-powered system, which can be implemented as a polymer-based electrode in advanced maintenance-free systems.

### Conflicts of interest

There are no conflicts to declare.

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